

Product Overview

NVMFD5C478N: Dual N-Channel Power MOSFET 40 V, 27 A, 17.0 m Ω

For complete documentation, see the data sheet.

Automotive Power MOSFET in a 5 x 6 mm flat lead package designed for compact and efficient designs and including high thermal performance. Wettable Flank Option available for Enhanced Optical Inspection. AEC-Q101 Qualified MOSFET and PPAP capable suitable for automotive applications.

Features

- · Low on resistance
- · High current capability
- · AEC-Q101 Qualified and PPAP Capable
- NVMFD5C478NWF Wettable Flanks Product
- · RoHS Compliant

Applications

- · Solenoid driver
- · Low side / high side driver

Benefits

- · Minimal conduction losses
- · Robust load performance
- Suitable for automotive applications
- · Enhanced Optical Inspection

End Products

- · Automotive engine controllers
- · Antilock braking systems

Part Electrical Specifications																	
Product	Pricing (\$/Unit)	Compliance	Statu s	Chan nel Polar ity	Confi gurati on	V _(BR) DSS Min (V)	V _{GS} Max (V)	V _{GS(th} Max (V)	I _D Max (A)	P _D Max (W)	$R_{DS(o)}$ Max $@$ $V_{GS} =$ 2.5 V $(m\Omega)$	$R_{DS(o)}$ Max $@$ $V_{GS} =$ 4.5 V $(m\Omega)$	$R_{DS(o}$ Max $@$ $V_{GS} =$ 10 V $(m\Omega)$	Q _g Typ @ V _{GS} = 4.5 V (nC)	Q _g Typ @ V _{GS} = 10 V (nC)	C _{iss} Typ (pF)	Pack age Type
NVMFD5C478NT1G		AEC Qualified PPAP Capable Pb-free Halide free	Activ e	N- Chan nel	Dual	40	20	4	24	18	-	-	14.7	-	7	350	SO- 8FL Dual / DFN- 8
NVMFD5C478NWFT1G		AEC Qualified PPAP Capable Pb-free Halide free	Activ e	N- Chan nel	Dual	40	20	4	24	18	-	-	14.7	-	7	350	SO- 8FL Dual / DFN- 8

For more information please contact your local sales support at www.onsemi.com.

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